

R&D technology adaptation

Improvement of cell efficiency to reduce

- carrier recombination loss
- optical absorption loss
- resistance loss

Application of three tabs

- Reducing electrical loss between the cell fingers and tabs
- Making the tab width thinner to expand the light receiving surface

New tab design

Anti-reflection glass

Light capturing technology

- Reducing reflection and scattering of incoming light
- Improving generated electricity levels in morning and evening times

19.0%*

190 W/m²



* For HIT-N240SE10

HIT cell technology

The SANYO HIT (Heterojunction with Intrinsic Thin layer) solar cell is made of a thin monocrystalline silicon wafer surrounded by ultra-thin amorphous silicon layers. This product provides the industry's leading performance and value using state-of-the-art manufacturing techniques.

Environmentally friendly solar cell

HIT can generate more clean energy than other conventional crystalline solar cells.

Special features

SANYO HIT solar modules are 100% emission free, have no moving parts and produce no noise. The dimensions of the HIT modules enable a space saving installation and the achievement of maximum output power possible on a given roof area.

High performance at high temperatures

Even at high temperatures, the HIT solar cell can maintain higher efficiency than a conventional crystalline silicon solar cell.

HIT[®] solar cell structure

Changes in generated power daytime

HIT[®]
Photovoltaic Module

HIT is a registered trademark of SANYO Electric Co., Ltd. The name "HIT" comes from "Heterojunction with intrinsic Thin-layer" which is an original technology of SANYO Electric Co., Ltd.

The HIT cell and module have very high conversion efficiency in mass production.

Model	Cell Efficiency	Module Efficiency	Output/m ²
HIT-N240SE10	21.6%	19.0%	190 W/m ²
HIT-N235SE10	21.1%	18.6%	186 W/m ²

Electrical data (at STC)

Models HIT-NxxxSE10

	240	235
Maximum power (Pmax) [W]	240	235
Max. power voltage (Vmp) [V]	43.7	43.0
Max. power current (Imp) [A]	5.51	5.48
Open circuit voltage (Voc) [V]	52.4	51.8
Short circuit current (Isc) [A]	5.85	5.84
Maximum over current rating [A]	15	
Output power tolerance [%]	+10/-5*	
Maximum system voltage [V]	1000	

Note: Standard Test Conditions: Air mass 1.5, Irradiance = 1000W/m², cell temperature = 25°C
 * All modules tested by SANYO facility have output with positive tolerance

Temperature characteristics

	240	235
Temperature (NOCT) [°C]	44.0	44.0
Temperature coefficient of Pmax [%/°C]	-0.30	-0.30
Temperature coefficient of Voc [V/°C]	-0.131	-0.130
Temperature coefficient of Isc [mA/°C]	1.76	1.75

At NOCT

	240	235
Maximum power (Pmax) [W]	182	179
Max. power voltage (Vmp) [V]	41.1	40.5
Max. power current (Imp) [A]	4.44	4.41
Open circuit voltage (Voc) [V]	49.4	48.9
Short circuit current (Isc) [A]	4.71	4.70

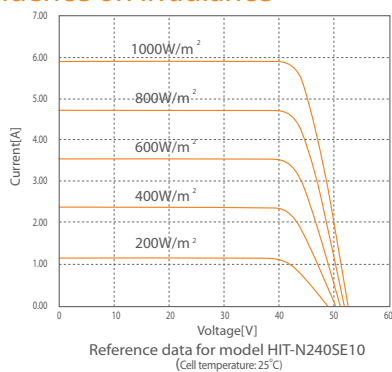
Note: Nominal Operating Cell Temperature : Air mass 1.5 spectrum, Irradiance = 800W/m², Air temperature = 20°C, wind speed 1 m/s

At low irradiance

	240	235
Maximum power (Pmax) [W]	45.9	44.7
Max. power voltage (Vmp) [V]	41.7	41.0
Max. power current (Imp) [A]	1.10	1.09
Open circuit voltage (Voc) [V]	49.0	48.4
Short circuit current (Isc) [A]	1.17	1.17

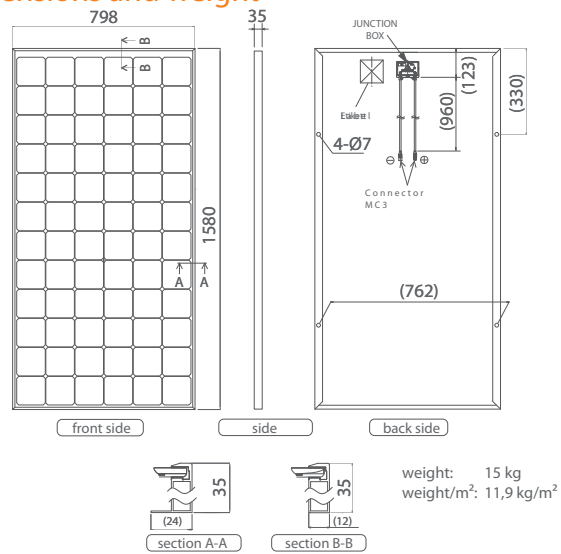
Note: Low irradiance: Air mass 1.5 spectrum, Irradiance = 200W/m², cell temperature = 25°C

Dependence on irradiance



Dimensions and weight

unit: mm



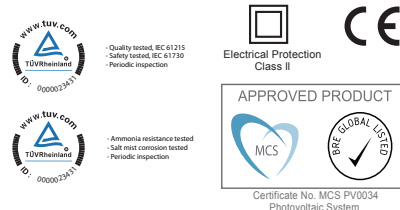
Guarantee

Power output: 10 years (90% of Pmin), 25 years (80% of Pmin)
 Product workmanship: 10 years
 (Based on guarantee document)

Materials

Cell material: 5 inch HIT cells
 Glass material: AR coated tempered glass
 Frame materials: Black anodized aluminium
 Connectors type: MC3

Certificates



Member of



Please consult your local dealer for more information.

CAUTION! Please read the installation manual carefully before using the products.

Due to our policy of continual improvement the products covered by this brochure may be changed without notice.